



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Re Application of

Bojarczuk, et al.

Serial No.: 09/755,164

Group Art Unit: 2826

Filed: January 8, 2001

Examiner: Quinto, Kevin V.

For: ALUMINUM NITRIDE AND ALUMINUM OXIDE/ALUMINUM NITRIDE
HETEROSTRUCTURE GATE DIELECTRIC STACK BASED FIELD EFFECT
TRANSISTORS AND METHOD FOR FORMING SAME

Commissioner for Patents
Washington, D.C. 20231

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PETITION AND FEE FOR EXTENSION OF TIME
UNDER 37 C.F.R. 1.136(a)

Sir:


Applicant hereby petitions for a One-month extension of time to respond to the Office Action mailed July 3, 2002. The Commissioner is hereby authorized to charge the extension fee in the amount of \$110.00 to Assignee's Deposit Account No. 50-0510. An Amendment responsive to the outstanding Office Action is being filed simultaneously herewith. A duplicate copy of this sheet is enclosed.

The Commissioner is hereby authorized to charge any deficiency in fees or to credit any overpayment in fees to Assignee's Deposit Account No. 50-0510.

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Respectfully submitted,

Date: 11/9/02


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